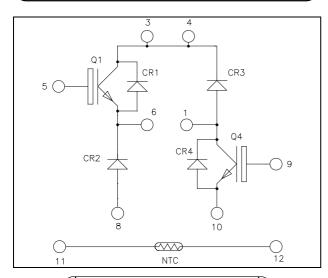
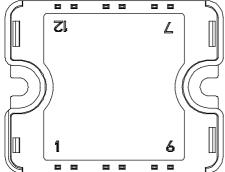


Asymmetrical - Bridge Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 600V$$

 $I_C = 50A*$ @ $Tc = 80°C$





Pins 3/4 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

| Symbol | Parameter | | Max ratings | Unit |
|-----------|---------------------------------------|----------------------------------|-------------|------|
| V_{CES} | Collector - Emitter Breakdown Voltage | | 600 | V |
| ī | Continuous Collector Current | $T_C = 25^{\circ}C$ | 80* | |
| I_{C} | Continuous Conector Current | $T_C = 80$ °C | 50* | Α |
| I_{CM} | Pulsed Collector Current | $T_C = 25$ °C | 100 | |
| V_{GE} | Gate – Emitter Voltage | | ±20 | V |
| P_{D} | Maximum Power Dissipation | $T_C = 25^{\circ}C$ | 176 | W |
| RBSOA | Reverse Bias Safe Operating Area | $T_{\rm J} = 150^{\circ}{\rm C}$ | 100A @ 550V | |

^{*} Specification of IGBT device but output current must be limited to 40A to not exceed a delta of temperature greater than 35°C for the connectors.

TAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|--|---------------------|-----|-----|-----|------|
| I_{CES} | Zero Gate Voltage Collector Current | $V_{GE} = 0V, V_{CE} = 600V$ | | | | 250 | μΑ |
| V _{CE(sat)} | Collector Emitter Saturation Voltage | $V_{GE} = 15V$ | $T_j = 25^{\circ}C$ | | 1.5 | 1.9 | V |
| V CE(sat) | | $I_{\rm C} = 50 {\rm A}$ $T_{\rm j} = 150 {\rm ^{\circ}C}$ | | 1.7 | | · | |
| $V_{GE(th)}$ | Gate Threshold Voltage | $V_{GE} = V_{CE}, I_C = 600 \mu A$ | | 5.0 | 5.8 | 6.5 | V |
| I_{GES} | Gate – Emitter Leakage Current | $V_{GE} = 20V, V_{CE} = 0V$ | | | | 600 | nA |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|------------------|------------------------------|---|----------------------------------|-----|------|-----|------|
| Cies | Input Capacitance | $V_{GE} = 0V$ | | | 3150 | | |
| Coes | Output Capacitance | $V_{CE} = 25V$ | | | 200 | | pF |
| C_{res} | Reverse Transfer Capacitance | f = 1MHz | | | 95 | | |
| Q_{G} | Gate charge | V _{GE} =±15V, I _C =50A V _{CE} =300V | | | 0.5 | | μС |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switch | ning (25°C) | | 110 | | ns |
| $T_{\rm r}$ | Rise Time | $V_{GE} = \pm 15V$ | | | 45 | | |
| $T_{d(off)}$ | Turn-off Delay Time | $V_{\text{Bus}} = 300 \text{V}$ $I_{\text{C}} = 50 \text{A}$ | | | 200 | | |
| $T_{\rm f}$ | Fall Time | $R_G = 8.2\Omega$ | | | 40 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switching (150°C) | | | 120 | | ns |
| $T_{\rm r}$ | Rise Time | | $V_{GE} = \pm 15V$ | | 50 | | |
| $T_{d(off)}$ | Turn-off Delay Time | $V_{\text{Bus}} = 300V$ $I_{\text{C}} = 50A$ | | | 250 | | |
| T_{f} | Fall Time | $R_G = 8.2\Omega$ | | | 60 | | |
| E _{on} | Turn-on Switching Energy | $V_{GE} = \pm 15V$ | $T_j = 25^{\circ}C$ | | 0.3 | | mJ |
| Lon | Turn-on Switching Energy | $V_{\text{Bus}} = 300V$ $T_{\text{j}} =$ | $T_{\rm j} = 150^{\circ}{\rm C}$ | | 0.43 | | 1113 |
| E_{off} | Turn-off Switching Energy | $I_C = 50A$ $R_G = 8.2\Omega$ | $T_j = 25^{\circ}C$ | | 1.35 | | mJ |
| 2011 | Tain on Switching Energy | | $T_j = 150$ °C | 1.7 | 1.75 | | 1113 |
| I_{sc} | Short Circuit data | $V_{GE} \le 15V$; V_{Bus} $t_p \le 6\mu s$; $T_i = 15$ | | | 250 | | A |

Diode ratings and characteristics (CR2 & CR3)

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|---------------------------|---|--|------------------------|-----|-----|-----|------|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | | 600 | | | V |
| I_{RM} | Maximum Reverse Leakage Current | V _R =600V | $T_j = 25^{\circ}C$ | | | 250 | μΑ |
| 1RM | Waximum Reverse Leakage Current | VR OOOV | $T_{j} = 150^{\circ}C$ | | | 500 | μΛ |
| I_F | DC Forward Current | | $Tc = 80^{\circ}C$ | | 50 | | Α |
| V_{F} | Diode Forward Voltage | $I_F = 50A$ $V_{GE} = 0V$ | $T_j = 25$ °C | | 1.6 | 2 | V |
| V F | Blode I of ward Voluge | | $T_i = 150$ °C | | 1.5 | | · |
| t _{rr} | Reverse Recovery Time | | $T_j = 25^{\circ}C$ | | 100 | | ns |
| ۲r | Reverse Recovery Time | , ,,, | $T_j = 150$ °C | | 150 | | 115 |
| | Daviana Dagayami Changa | $I_F = 50A$ $V_R = 300V$ $di/dt = 1800A/\mu s$ | $T_j = 25^{\circ}C$ | | 2.6 | | μС |
| Q_{rr} | Reverse Recovery Charge | | $T_j = 150$ °C | | 5.4 | | μС |
| E_{r} | Reverse Recovery Energy | | $T_j = 25^{\circ}C$ | | 0.6 | | mJ |
| $\mathbf{L}_{\mathbf{r}}$ | Reverse Recovery Energy | | $T_{j} = 150^{\circ}C$ | | 1.2 | | 1113 |

CR1 & CR4 are IGBT protection diodes only



Thermal and package characteristics

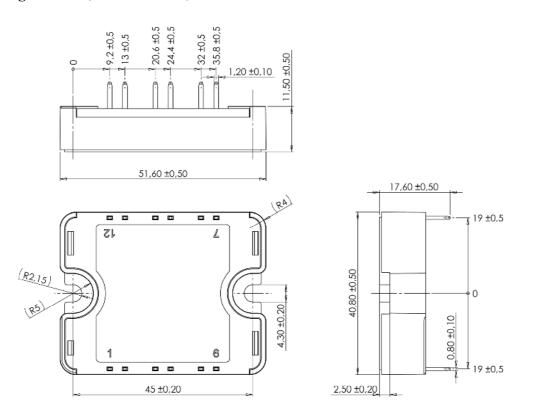
| Symbol | Characteristic | | | Min | Typ | Max | Unit |
|------------------|---|-------------|-------|------|------|------|------|
| R_{thJC} | Junction to Case Thermal Resistance | IGBT | | | 0.85 | °C/W | |
| KthJC | Junction to Case Thermal Resistance | | Diode | | | | C/ W |
| V_{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | | 4000 | | | V |
| T_{J} | Operating junction temperature range | | | -40 | | 175 | |
| T _{STG} | Storage Temperature Range | | | -40 | | 125 | °C |
| $T_{\rm C}$ | Operating Case Temperature | | | -40 | | 100 | |
| Torque | Mounting torque | To heatsink | M4 | 2 | | 3 | N.m |
| Wt | Package Weight | | | | 80 | g | |

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

| Symbol | Characteristic | acteristic | | Typ | Max | Unit |
|------------------------|-----------------------------|-----------------------|--|------|-----|------|
| R ₂₅ | Resistance @ 25°C | | | 50 | | kΩ |
| $\Delta R_{25}/R_{25}$ | | | | 5 | | % |
| ${ m B}_{25/85}$ | $T_{25} = 298.15 \text{ K}$ | | | 3952 | | K |
| $\Delta \mathrm{B/B}$ | | T _C =100°C | | 4 | | % |

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

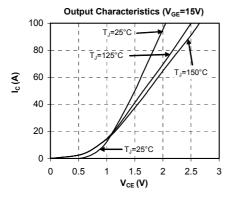
SP1 Package outline (dimensions in mm)

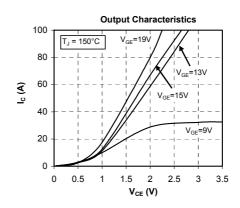


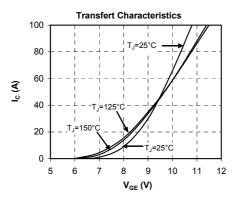
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

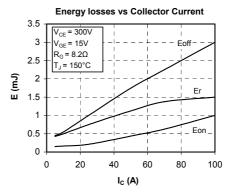


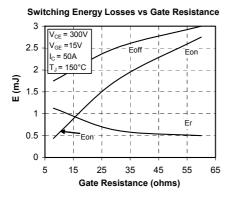
Typical Performance Curve

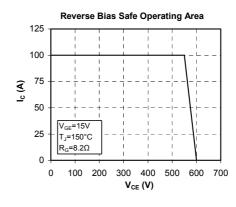


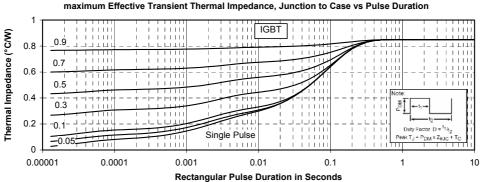




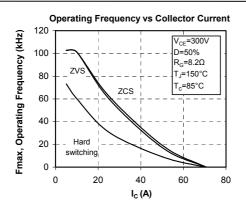


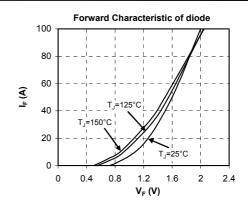


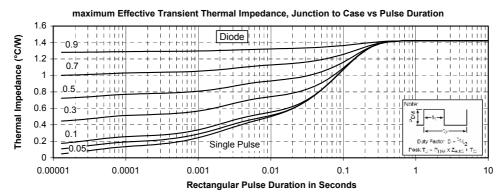












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